

Low-Voltage Dual SPST Analog Switch

DESCRIPTION

The DG9232/9233 is a single-pole/single-throw monolithic CMOS analog device designed for high performance switching of analog signals. Combining low power, high speed (t_{ON} : 35 ns, t_{OFF} : 20 ns), low on-resistance ($r_{DS(on)}$: 20 Ω) and small physical size, the DG9232/9233 is ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG9232/9233 is built on Vishay Siliconix's low voltage BCD-15 process. Minimum ESD protection, per Method 3015.7 is 2000 V. An epitaxial layer prevents latchup. Break-before -make is guaranteed for DG9232/9233.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

BENEFITS

- Reduced Power Consumption
- Simple Logic Interface
- High Accuracy
- Reduce Board Space

FEATURES

- Low Voltage Operation (+ 2.7 to + 5 V)
- Low On-Resistance - $r_{DS(on)}$: 20 Ω
- Fast Switching - t_{ON} : 35 ns, t_{OFF} : 20 ns
- Low Leakage - $I_{COM(on)}$: 200 pA max
- Low Charge Injection - Q_{INJ} : 1 pC
- Low Power Consumption
- TTL/CMOS Compatible
- ESD Protection > 2000 V (Method 3015.7)
- Available in MSOP-8 and SOIC-8

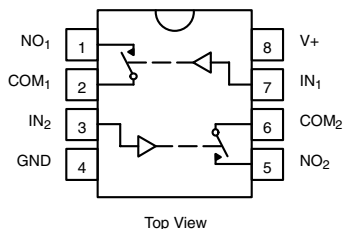
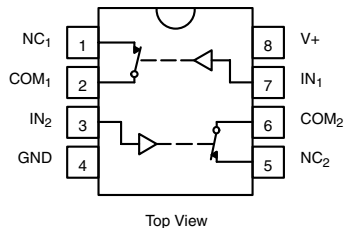


Available
RoHS*
COMPLIANT

APPLICATIONS

- Battery Operated Systems
- Portable Test Equipment
- Sample and Hold Circuits
- Cellular Phones
- Communication Systems
- Military Radio
- PBX, PABX Guidance and Control Systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE - DG9232

| Logic | Switch |
|-------|--------|
| 0 | ON |
| 1 | OFF |

Logic "0" ≤ 0.8 V
Logic "1" ≥ 2.4 V

TRUTH TABLE - DG9233

| Logic | Switch |
|-------|--------|
| 0 | OFF |
| 1 | ON |

Logic "0" ≤ 0.8 V
Logic "1" ≥ 2.4 V

ORDERING INFORMATION

| Temp Range | Package | Part Number |
|-------------------------|---------|--|
| - 40 to 85 $^{\circ}$ C | SOIC-8 | DG9232DY DG9232DY-E3 DG9232DY-T1 DG9232DY-T1-E3 |
| | | DG9233DY DG9233DY-E3 DG9233DY-T1 DG9233DY-T1-E3 |
| | MSOP-8 | DG9232DQ-T1-E3 |
| | | DG9233DQ-T1-E3 |

* Pb containing terminations are not RoHS compliant, exemptions may apply

ABSOLUTE MAXIMUM RATINGS

| Parameter | Limit | Unit |
|--|-------------------------------------|------|
| Reference V+ to GND | - 0.3 to + 13 | V |
| IN, COM, NC, NO ^a | - 0.3 to (V+ + 0.3) | |
| Continuous Current (Any terminal) | ± 20 | mA |
| Peak Current (Pulsed at 1 ms, 10 % duty cycle) | ± 40 | |
| ESD (Method 3015.7) | > 2000 | V |
| Storage Temperature | D Suffix | °C |
| Power Dissipation (Packages) ^b | 8-Pin Narrow Body SOIC ^c | mW |

Notes:

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC Board.

c. Derate 6.5 mW/°C above 70 °C.

SPECIFICATIONS (V+ = 3 V)

| Parameter | Symbol | Test Conditions Otherwise Unless Specified V+ = 3 V, ± 10 %, V _{IN} = 0.8 V or 2.4 V ^e | Temp ^a | D Suffix - 40 to 85 °C | | | Unit |
|---|--------------------------------------|--|-------------------|---------------------------|------------------|------------------|------|
| | | | | Min ^c | Typ ^b | Max ^c | |
| Analog Switch | | | | | | | |
| Analog Signal Range ^d | V _{ANALOG} | | Full | 0 | | 3 | V |
| Drain-Source On-Resistance | r _{DS(on)} | V _{NO} or V _{NC} = 1.5 V, V+ = 2.7 V I _{COM} = 5 mA | Room Full | | 30 | 50 80 | Ω |
| r _{DS(on)} Match ^d | Δr _{DS(on)} | V _{NO} or V _{NC} = 1.5 V | Room | | 0.4 | 2 | |
| r _{DS(on)} Flatness ^d | r _{DS(on)} Flatness | V _{NO} or V _{NC} = 1 and 2 V | Room | | 4 | 8 | |
| NO or NC Off Leakage Current ^g | I _{NO/NC(off)} | V _{NO} or V _{NC} = 1 V/2 V, V _{COM} = 2 V/1 V | Room Full | - 100 - 5000 | 5 | 100 5000 | pA |
| COM Off Leakage Current ^g | I _{COM(off)} | V _{COM} = 1 V/2 V, V _{NO} or V _{NC} = 2 V/1 V | Room Full | - 100 - 5000 | 5 | 100 5000 | |
| Channel-On Leakage Current ^g | I _{COM(on)} | V _{COM} = V _{NO} or V _{NC} = 1 V/2 V | Room Full | - 200 - 10000 | 10 | 200 10000 | |
| Digital Control | | | | | | | |
| Input Current | I _{INL} or I _{INH} | | Full | | 1 | | μA |
| Dynamic Characteristics | | | | | | | |
| Turn-On Time | t _{ON} | V _{NO} or V _{NC} = 1.5 V | Room Full | | 50 | 120 200 | ns |
| Turn-Off Time | t _{OFF} | | Room Full | | 20 | 50 120 | |
| Charge Injection ^d | Q _{INJ} | C _L = 1 nF, V _{GEN} = 0 V, R _{GEN} = 0 Ω | Room | | 1 | 5 | pC |
| Off-Isolation | OIRR | R _L = 50 Ω, C _L = 5 pF, f = 1 MHz | Room | | - 74 | | dB |
| Crosstalk | X _{TALK} | | Room | | - 90 | | |
| NC and NO Capacitance | C _{S(off)} | f = 1 MHz | Room | | 7 | | pF |
| Channel-On Capacitance | C _{COM(on)} | | Room | | 20 | | |
| COM-Off Capacitance | C _{COM(off)} | | Room | | 13 | | |
| Power Supply | | | | | | | |
| Positive Supply Range | V+ | | | 2.7 | | 12 | V |
| Power Supply Current | I+ | V+ = 3.3 V, V _{IN} = 0 or 3.3 V | | | | 1 | μA |

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

b. Typical values are for design aid only, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

d. Guarantee by design, nor subjected to production test.

e. V_{IN} = input voltage to perform proper function.

f. Difference of min and max values.

g. Guaranteed by 5-V leakage tests, not production tested.



| SPECIFICATIONS (V+ = 5 V) | | | | | | | |
|---|---------------------|--|-------------------|--------------------------|------------------|------------------|------|
| Parameter | Symbol | Test Conditions Otherwise Unless Specified V+ = 5 V, ± 10 %, VIN = 0.8 V or 2.4 V ^e | Temp ^a | D Suffix - 40 to 85°C | | | Unit |
| | | | | Min ^c | Typ ^b | Max ^c | |
| Analog Switch | | | | | | | |
| Analog Signal Range ^d | VANALOG | | Full | 0 | | 5 | V |
| Drain-Source On-Resistance | rDS(on) | VNO or VNC = 3.5 V, V+ = 4.5 V ICOM = 5 mA | Room Full | | 20 | 30 50 | Ω |
| rDS(on) Match ^d | ΔrDS(on) | VNO or VNC = 3.5 V | Room | | 0.4 | 2 | |
| rDS(on) Flatness ^d | rDS(on) Flatness | VNO or VNC = 1, 2 and 3 V | Room | | 2 | 6 | |
| NO or NC Off Leakage Current ^g | INO/NC(off) | VNO or VNC = 1 V/4 V, VCOM = 4 V/1 V | Room Full | - 100 - 5000 | 10 | 100 5000 | pA |
| COM Off Leakage Current | ICOM(off) | VCOM = 1 V/4 V, VNO or VNC = 4 V/1 V | Room Full | - 100 - 5000 | 10 | 100 5000 | |
| Channel-On Leakage Current | ICOM(on) | VCOM = VNO or VNC = 1 V/4 V | Room Full | - 200 - 10000 | | 200 10000 | |
| Digital Control | | | | | | | |
| Input Current | IINL or IINH | | Full | | 1 | | μA |
| Dynamic Characteristics | | | | | | | |
| Turn-On Time | tON | VNO or VNC = 3.0 V | Room Full | | 35 | 75 150 | ns |
| Turn-Off Time | tOFF | | Room Full | | 20 | 50 100 | |
| Charge Injection ^d | QINJ | CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω | Room | | 2 | 5 | pC |
| Off-Isolation | OIRR | RL = 50 Ω, CL = 5 pF, f = 1 MHz | Room | | - 74 | | dB |
| Crosstalk | XTALK | | Room | | - 90 | | |
| NC and NO Capacitance | C(off) | f = 1 MHz | Room | | 7 | | pF |
| Channel-On Capacitance | CD(on) | | Room | | 20 | | |
| COM-Off Capacitance | CD(off) | | Room | | 13 | | |
| Power Supply | | | | | | | |
| Positive Supply Range | V+ | | | 2.7 | | 12 | V |
| Power Supply Current | I+ | V+ = 5.5 V, VIN = 0 or 5.5 V | | | | 1 | μA |

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

b. Typical values are for design aid only, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

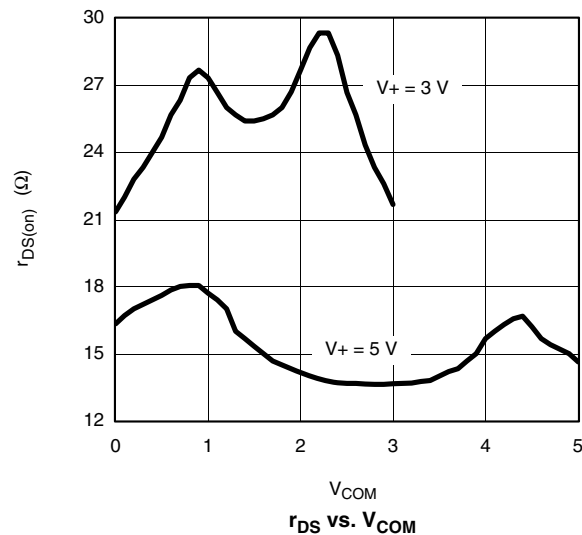
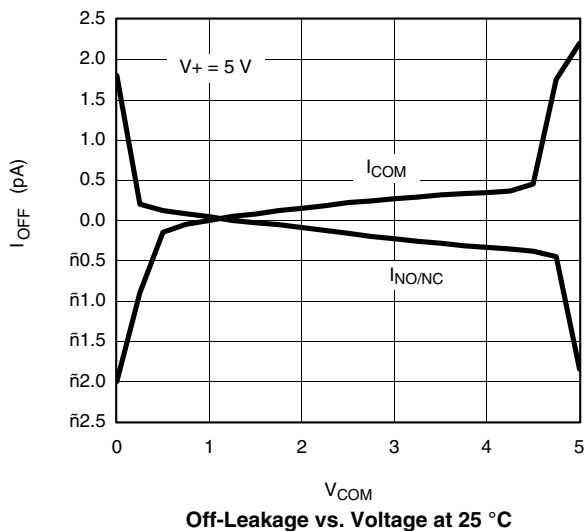
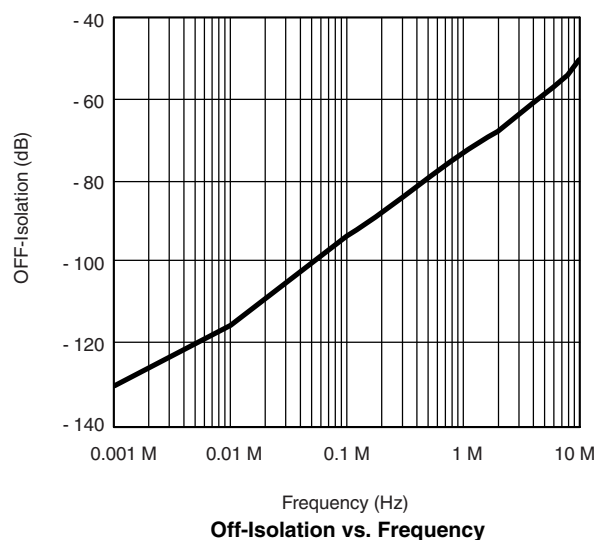
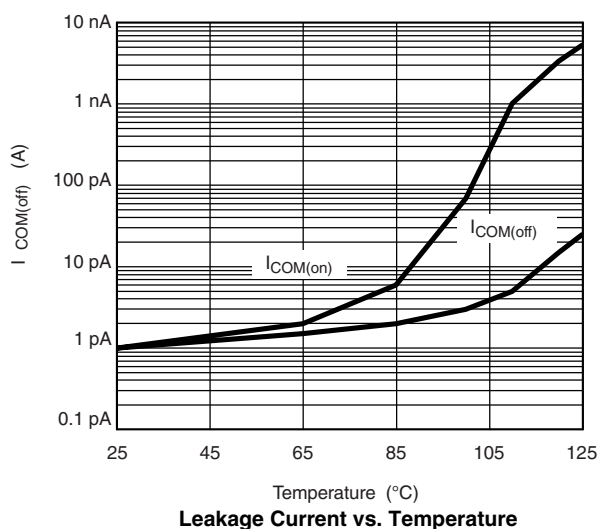
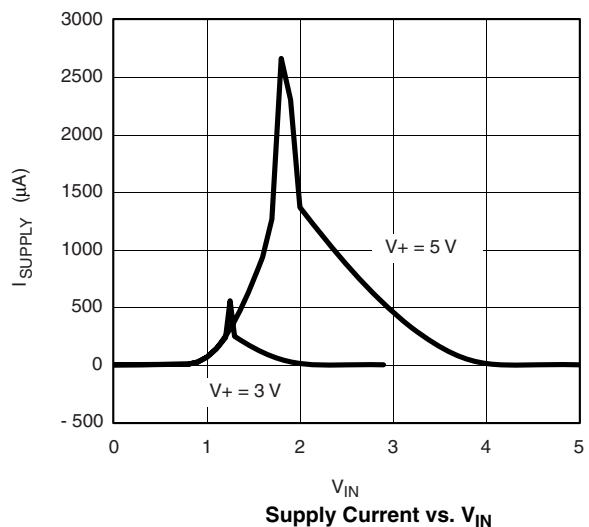
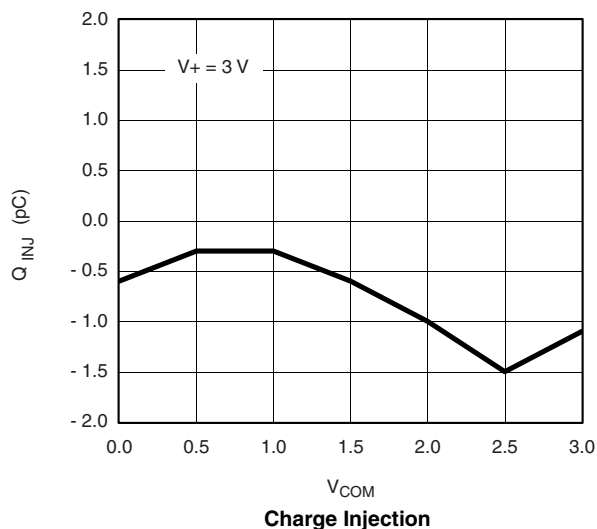
d. Guarantee by design, nor subjected to production test.

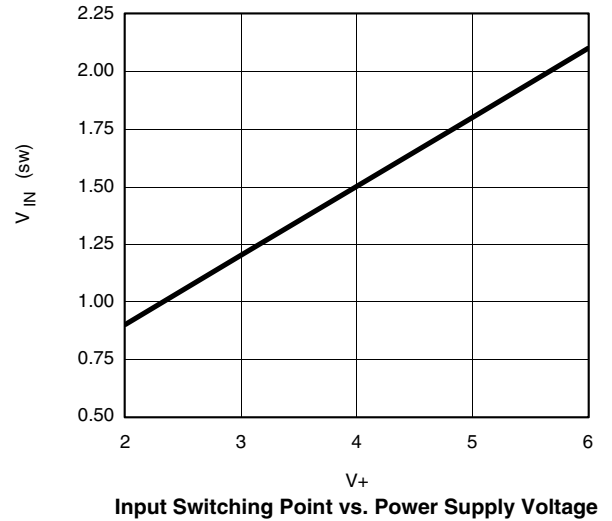
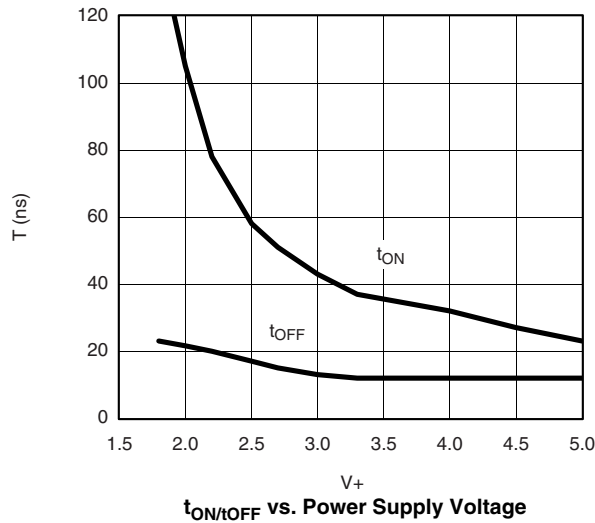
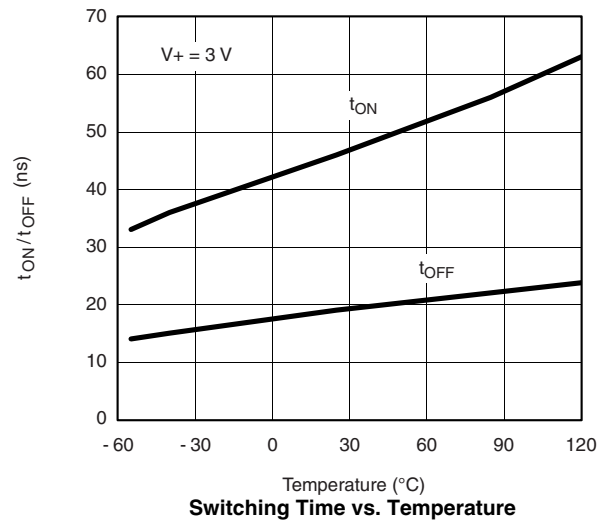
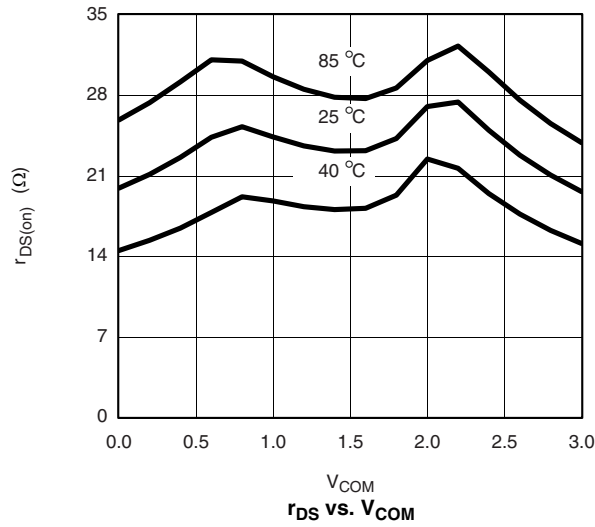
e. V_{IN} = input voltage to perform proper function.

f. Difference of min and max values.

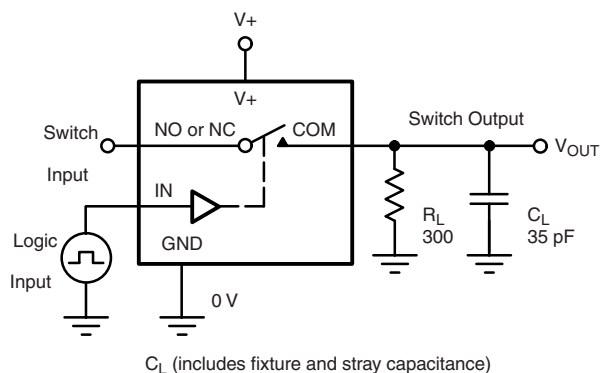
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, unless otherwise noted

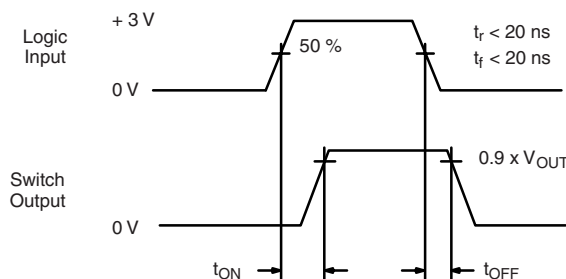


TYPICAL CHARACTERISTICS $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted


TEST CIRCUITS



$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

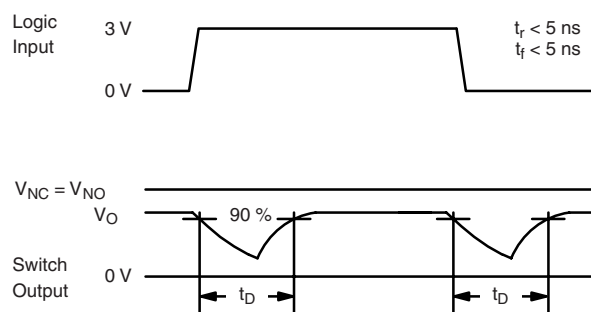
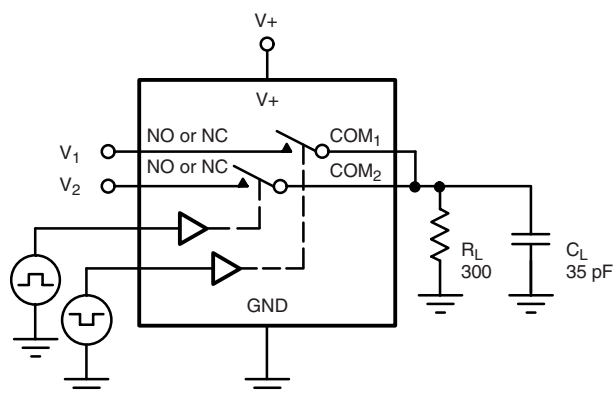
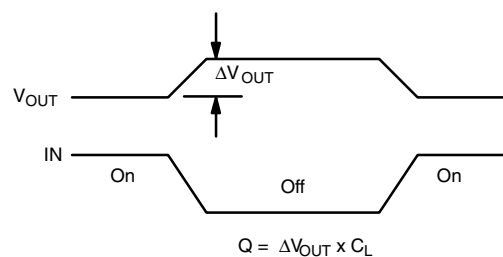
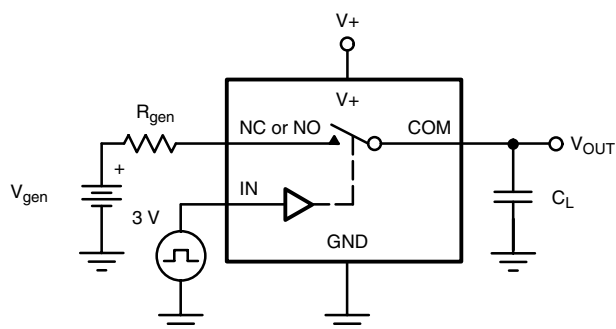
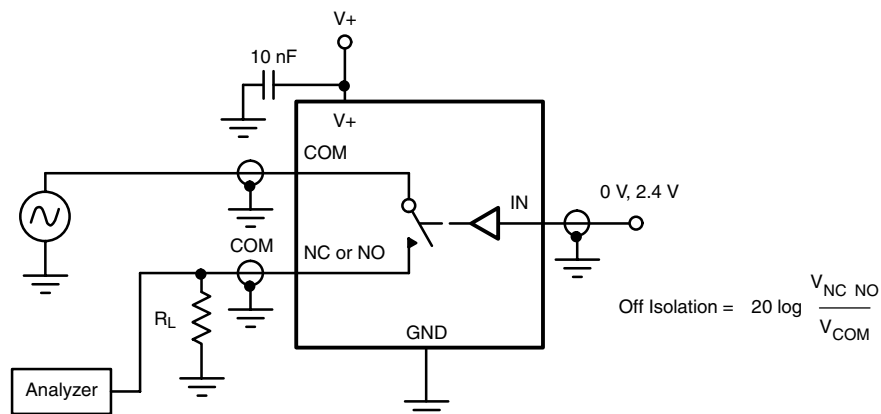
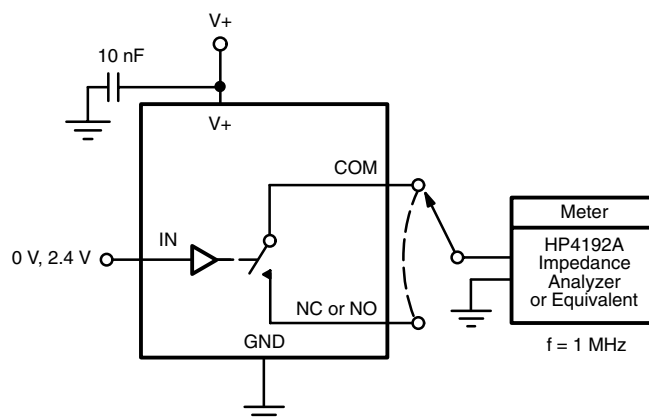


Figure 2. Break-Before-Make Interval



IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection

TEST CIRCUITS

Figure 4. Off-Isolation

Figure 5. Channel Off/On Capacitance

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